# International Rectifier

# IRS2301S HIGH AND LOW SIDE DRIVER

#### **Features**

- Floating channel designed for bootstrap operation
- Fully operational to +600V
- Tolerant to negative transient voltage dV/dt immune
- Gate drive supply range from 5V to 20V
- Undervoltage lockout for both channels
- 3.3V, 5V and 15V input logic compatible
- · Matched propagation delay for both channels
- Outputs in phase with inputs
- Lower di/dt gate driver for better noise immunity
- Leadfree, RoHS compliant

#### **Typical Applications**

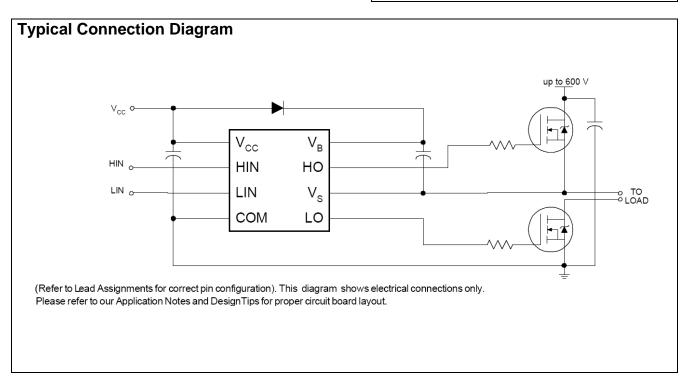
- Appliance motor drives
- Servo drives
- Micro inverter drives
- o General purpose three phase inverters

#### **Product Summary**

V <sub>OFFSET</sub>	600V Max
V <sub>OUT</sub>	5V – 20V
I <sub>0+</sub> & I <sub>0-</sub> (min)	120mA / 250mA
t <sub>ON</sub> & t <sub>OFF</sub> (typical)	220ns / 200ns
Delay Matching	50ns

**Package Options** 





# **IRS2301S**

# International TOR Rectifier

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**IRS2301S** 

International **TOR** Rectifier

#### **Description**

The IRS2301S is a high voltage, high speed power MOSFET and IGBT driver with independent high- and low-side referenced output channels. Proprietary HVIC and latch immune CMOS technologies enable ruggedized monolithic construction. The logic input is compatible with standard CMOS or LSTTL output, down to 3.3V logic. The output drivers feature a high pulse current buffer stage. The floating channel can be used to drive an N-channel power MOSFET or IGBT in the high-side configuration which operates up to 600V.



#### Qualification Information<sup>†</sup>

		Industrial <sup>††</sup>		
Qualification Level		Comments: This family of ICs has passed JEDEC's		
		Industrial qualification. IR's Consumer qualification level		
		is granted by extension of the higher Industrial level.		
Moisture Sensitivity Level		MSL2 <sup>†††</sup> 260°C		
		(per IPC/JEDEC J-STD-020)		
	Machine Model	Class B		
ESD	Macrime Model	(per JEDEC standard JESD22-A115)		
230	Human Bady Madal	Class 2		
	Human Body Model	(per EIA/JEDEC standard EIA/JESD22-A114)		
IC Latabilia Taat		Class I, Level A		
IC Latch-Up Test		(per JESD78)		
RoHS Compliant		Yes		

- † Qualification standards can be found at International Rectifier's web site <a href="http://www.irf.com/">http://www.irf.com/</a>
- †† Higher qualification ratings may be available should the user have such requirements. Please contact your International Rectifier sales representative for further information.
- ††† Higher MSL ratings may be available for the specific package types listed here. Please contact your International Rectifier sales representative for further information.

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#### **Absolute Maximum Ratings**

Absolute Maximum Ratings indicate sustained limits beyond which damage to the device may occur. All voltage parameters are absolute voltages referenced to COM. The thermal resistance and power dissipation ratings are measured under board mounted and still air conditions.

Symbol	Definition	Min.	Max.	Units			
$V_B$	High-side floating absolute voltage	-0.3	625				
Vs	High-side floating supply offset voltage	V <sub>B</sub> - 25	V <sub>B</sub> + 0.3				
$V_{HO}$	High-side floating output voltage	V <sub>S</sub> - 0.3	V <sub>B</sub> + 0.3				
$V_{CC}$	Low-side and logic fixed supply voltage	-0.3	25	V			
$V_{LO}$	Low-side output voltage	-0.3	V <sub>CC</sub> + 0.3				
$V_{IN}$	Logic input voltage (HIN & LIN)	COM -0.3	$V_{CC} + 0.3$				
dV <sub>S</sub> /dt	Allowable offset supply voltage transient	_	50	V/ns			
$P_D$	Package power dissipation @ TA ≤ 25°C	_	0.625	W			
Rth <sub>JA</sub>	Thermal resistance, junction to ambient	_	200	°C/W			
$T_J$	Junction temperature	_	150				
Ts	Storage temperature	rage temperature -50 150					
T <sub>L</sub>	Lead temperature (soldering, 10 seconds)	_	300				

#### **Recommended Operating Conditions**

The input/output logic timing diagram is shown in Fig. 1. For proper operation the device should be used within the recommended conditions. The  $V_s$  offset rating is tested with all supplies biased at 15V differential.

Symbol	Definition	Min.	Max.	Units			
$V_{B}$	High-side floating supply absolute voltage	V <sub>S</sub> + 5	V <sub>S</sub> + 20	20			
Vs	High-side floating supply offset voltage	† 1	600				
$V_{HO}$	High-side floating output voltage	$V_B$	V				
V <sub>CC</sub>	Low-side and logic fixed supply voltage	5	20	V			
$V_{LO}$	Low-side output voltage	0	$V_{CC}$				
V <sub>IN</sub>	Logic input voltage (HIN & LIN) COM V <sub>CC</sub>						
T <sub>A</sub>	Ambient temperature	-40	125	°C			

<sup>†:</sup> Logic operational for  $V_S$  of -5 V to +600 V. Logic state held for  $V_S$  of -5 V to  $-V_{BS}$ . (Please refer to the Design Tip DT97 -3 for more details).

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#### **Static Electrical Characteristics**

 $V_{BIAS}$  ( $V_{CC}$ ,  $V_{BS}$ ) = 15V and  $T_A$  = 25°C unless otherwise specified. The  $V_{IL}$ ,  $V_{IH}$  and  $I_{IN}$  parameters are referenced to COM and are applicable to the respective input leads: HIN and LIN. The  $V_{O_i}$   $I_{O_i}$  and  $I_{O_i}$  parameters are referenced to COM and are applicable to the respective output leads: HO and LO.

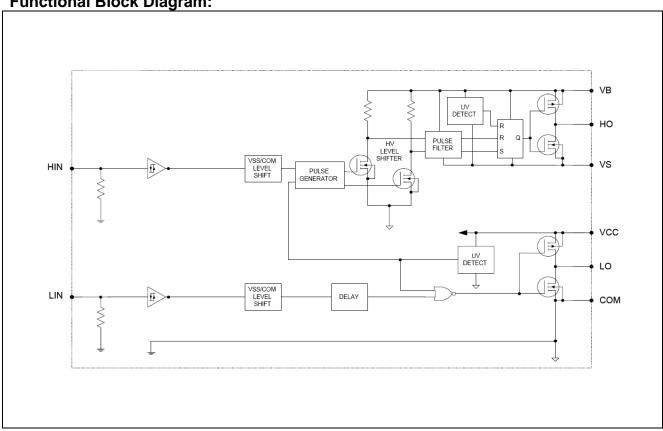
Symbol	Definition	Min	Тур	Max	Units	Test conditions	
$V_{IH}$	Logic "1" input voltage	2.5	_	_	V	V <sub>CC</sub> = 10V to 20V	
$V_{IL}$	Logic "0" input voltage	_	_	0.8	V		
$V_{OH}$	High level output voltage, V <sub>BIAS</sub> - V <sub>O</sub>	_	_	0.2	V	l - 0 - Λ	
V <sub>OL</sub>	Low level output voltage, V <sub>O</sub>	_	_	0.1	V	I <sub>O</sub> = 2mA	
$I_{LK}$	Offset supply leakage current	_	_	50		$V_{B} = V_{S} = 600V$	
$I_{QBS}$	Quiescent V <sub>BS</sub> supply current	60	160	260		V <sub>IN</sub> = 0V or 5V	
I <sub>QCC</sub>	Quiescent V <sub>CC</sub> supply current	60	160	260	μA	V <sub>IN</sub> = 0 V 01 5 V	
$I_{IN+}$	Logic "1" input bias current	_	5	20		$V_{IN} = 5V$	
$I_{IN-}$	Logic "0" input bias current	_		5		$V_{IN} = 0V$	
$V_{CCUV+} \ V_{BSUV+}$	V <sub>CC</sub> and V <sub>BS</sub> supply undervoltage positive going threshold	3.3	4.1	5			
$V_{CCUV-} V_{BSUV-}$	V <sub>CC</sub> and V <sub>BS</sub> supply undervoltage negative going threshold		3.8	4.7	V		
$V_{\text{CCUVH}}$ $V_{\text{BSUVH}}$	Hysteresis	0.1	0.3	—			
I <sub>O+</sub>	Output high short circuit pulsed current — 200 — mA		V <sub>O</sub> = 0V, PW ≤ 10µs				
I <sub>O-</sub>	Output low short circuit pulsed current	_	350	_	ША	V <sub>O</sub> = 15V, PW ≤ 10µs	

#### **Dynamic Electrical Characteristics**

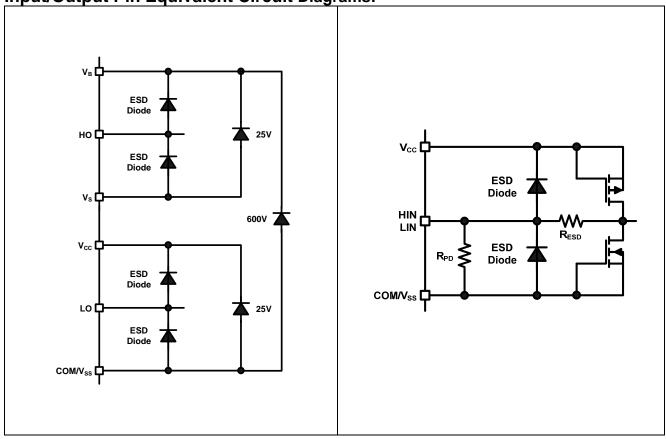
 $V_{BIAS}$  ( $V_{CC}$ ,  $V_{BS}$ ) = 15V,  $C_L$  = 1000pF,  $T_A$  = 25°C unless otherwise specified.

Symbol	Definition	Min	Тур	Max	Units	Test conditions
t <sub>on</sub>	Turn-on propagation delay	_	220	300		$V_S = 0V$
t <sub>off</sub>	Turn-off propagation delay	_	200	280		$V_S = 0V \text{ or } 600V$
MT	Delay matching, HS & LS turn-on/off	_	0	50	ns	
t <sub>r</sub>	Turn-on rise time	_	130	220		V <sub>S</sub> = 0V
t <sub>f</sub>	Turn-off fall time	_	50	80		v <sub>S</sub> - 0v

Functional Block Diagram:



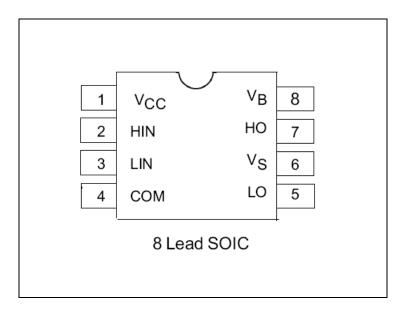
**Input/Output Pin Equivalent Circuit Diagrams:** 



#### **Lead Definitions:**

PIN#	Symbol	Description					
1	$V_{CC}$	Low-side and logic fixed supply					
2	HIN	ogic input for high-side gate driver outputs (HO), in phase with HO					
3	LIN	Logic input for low-side gate driver outputs (LO), in phase with LO					
4	COM	Low-side return					
5	LO	Low-side gate drive output					
6	$V_S$	High-side floating supply return					
7	НО	High-side gate drive output					
8	$V_B$	High-side floating supply					

# **Lead Assignments**



# **Application Information and Additional Details**

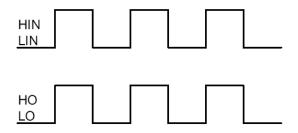
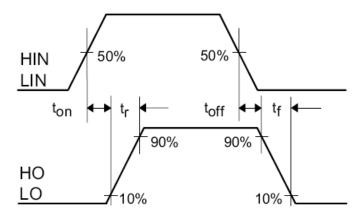
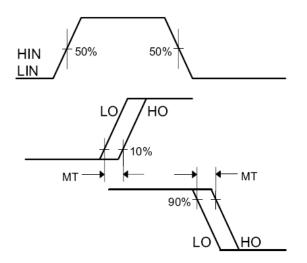


Figure 1: Input/Output Timing Diagram



**Figure 2: Switching Time Waveform Definitions** 



**Figure 3: Delay Matching Waveform Definitions** 

#### **Tolerability to Negative VS Transients**

The IRS2301S has been seen to withstand negative  $V_S$  transient conditions on the order of -25V for a period of 100 ns ( $V_{BIAS}$  ( $V_{CC}$ ,  $V_{BS}$ ) = 15V and  $T_A$  = 25°C).

An illustration of the IRS2301S performance can be seen in Figure 4.

Even though the IRS2301S has been shown able to handle these negative Vs transient conditions, it is highly recommended that the circuit designer always limit the negative Vs transients as much as possible by careful PCB layout and component use.

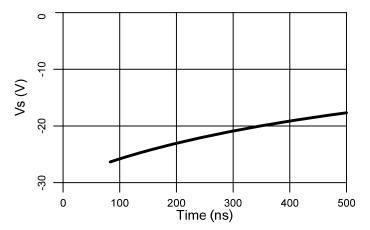
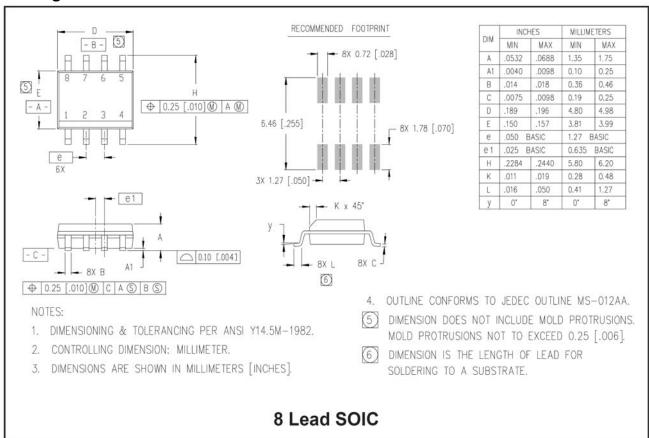


Figure 4: -Vs Transient results

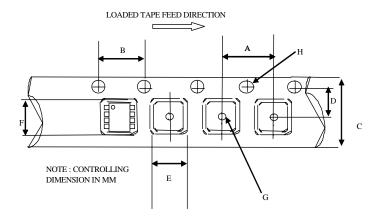
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# **IRS2301S**

#### **Package Details**

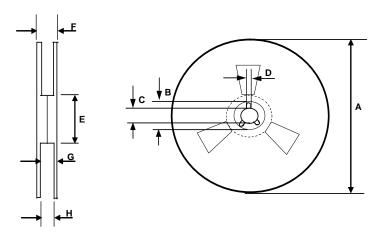


# Tape and Reel Details



CARRIER TAPE DIMENSION FOR 8SOICN

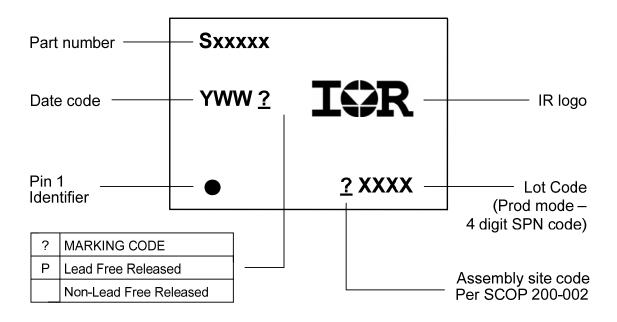
	Metric		Imperial		
Code	Min	Max	Min	Max	
Α	7.90	8.10	0.311	0.318	
В	3.90	4.10	0.153	0.161	
С	11.70	12.30	0.46	0.484	
D	5.45	5.55	0.214	0.218	
E	6.30	6.50	0.248	0.255	
F	5.10	5.30	0.200	0.208	
G	1.50	n/a	0.059	n/a	
Н	1.50	1.60	0.059	0.062	



REEL DIMENSIONS FOR 8SOICN

RELE DIVIENSIONS FOR 830ICN							
	Metric		Imperial				
Code	Min	Max	Min	Max			
Α	329.60	330.25	12.976	13.001			
В	20.95	21.45	0.824	0.844			
С	12.80	13.20	0.503	0.519			
D	1.95	2.45	0.767	0.096			
E	98.00	102.00	3.858	4.015			
F	n/a	18.40	n/a	0.724			
G	14.50	17.10	0.570	0.673			
Н	12.40	14.40	0.488	0.566			

#### **Part Marking Information**





#### **Ordering Information**

Danie Barri Namelan	Baalama Tama	Standard Pack		Occupation Book Named an	
Base Part Number	Package Type	Form	Quantity	Complete Part Number	
ID00004	SOIC8N	Tube/Bulk	95	IRS2301SPBF	
IRS2301	3010011	Tape and Reel	2500	IRS2301STRPBF	

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0134220000 60713816 M15730061 61161-90 61278-0020 6131-204-23149P 6131-205-17149P 6131-209-15149P 6131-218-17149P 6131220-21149P 6131-260-2358P 6131-265-11149P CS1HCPU63